NSN 5962-01-384-4824

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range: -55.0/+125.0 degrees celsius Features Provided:

Programmed and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

15.00 nanoseconds af output torr

Memory Device Type:

Pal

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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